



#### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
-60V	8Ω @ V <sub>GS</sub> = -5V	-238mA

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- DC-DC converters
- Power-management functions

### **Features and Benefits**

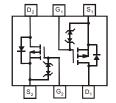
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Qsuffix) part. A listing can be found at <a href="https://www.diodes.com/products/automotive/automotive-au
- products/.
  This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
  - https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 63
- Weight: 0.006 grams (Approximate)







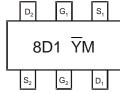
#### **Ordering Information** (Note 4)

Part Number	Dookono	Packing		
Part Number	Package	Qty.	Carrier	
DMP68D1LV-7	SOT563	3000	Tape & Reel	
DMP68D1LV-13	SOT563	10000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



8D1 = Product Type Marking Code  $\overline{Y}M$  = Date Code Marking  $\overline{Y}$  = Year (ex: K = 2023) M = Month ex: (5 = May)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	K	L	М	N	Р	R	S	Т	U	V	W	Χ
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		VDSS	-60	V	
Gate-Source Voltage			$V_{GSS}$	±20	V
Continuous Drain Current (Note 6) $V_{GS} = -5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			lo	-238 -190	mA
Maximum Continuous Body Diode Forward Curren	t (Note 6)	Is	-238	mA	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	6)	IDM	-1	Α	
Pulsed Source Current (10µs Pulse, Duty Cycle =	1%)		lsм	-1	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_D$	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	258	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	0.8	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	151	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Oymboi	141111	ıур	IVIGA	Oint	rest condition	
Drain-Source Breakdown Voltage	BVDSS	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μΑ	V <sub>DS</sub> = -60V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.8	_	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	2.0	8	Ω	$V_{GS} = -5V, I_{D} = -100mA$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.8	-1.5	V	$V_{GS} = 0V, I_{S} = -100mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	42	_		.,	
Output Capacitance	Coss	_	10	_	pF	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	6	_		T = 1.0MHZ	
Gate Resistance	Rg	_	225	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg		0.6	_			
Gate-Source Charge	Qgs	_	0.1	_	nC	$V_{GS} = -5V, V_{DS} = -30V,$ $I_{D} = -100mA$	
Gate-Drain Charge	Qgd	_	0.2	_			
Turn-On Delay Time	t <sub>D</sub> (ON)	_	11	_			
Turn-On Rise Time	t <sub>R</sub>	_	16	_	٦.,	$V_{GS} = -5V, V_{DS} = -30V,$	
Turn-Off Delay Time	tD(OFF)	_	30	_	ns	$R_G = 50\Omega$ , $I_D = -100 \text{mA}$	
Turn-Off Fall Time	tF	_	30	_	1		

Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
   Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.



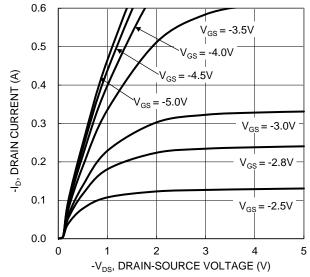


Figure 1. Typical Output Characteristic

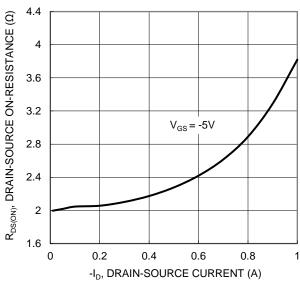


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

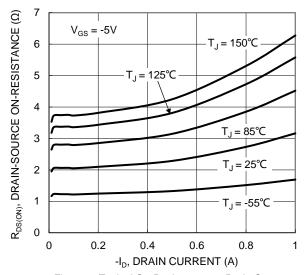


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

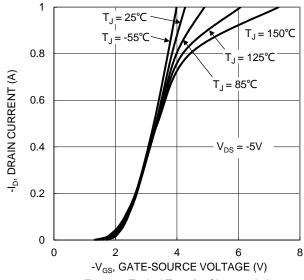


Figure 2. Typical Transfer Characteristic

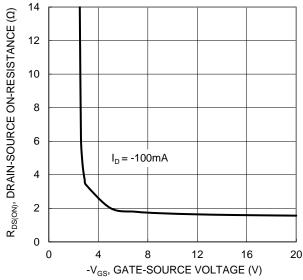


Figure 4. Typical Transfer Characteristic

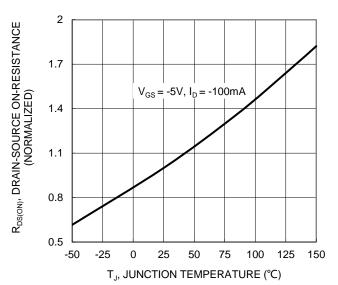


Figure 6. On-Resistance Variation with Junction Temperature



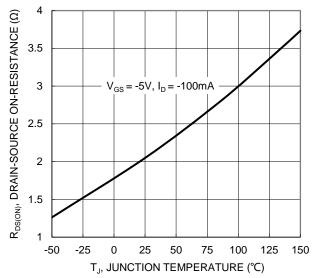


Figure 7. On-Resistance Variation with Junction Temperature

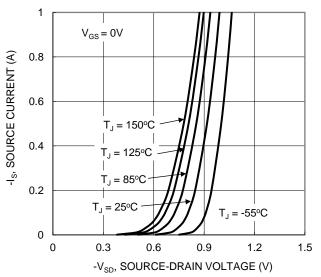


Figure 9. Diode Forward Voltage vs. Current

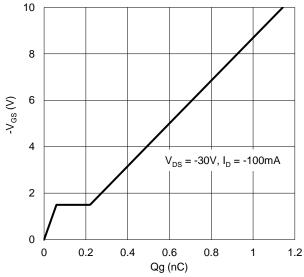


Figure 11. Gate Charge

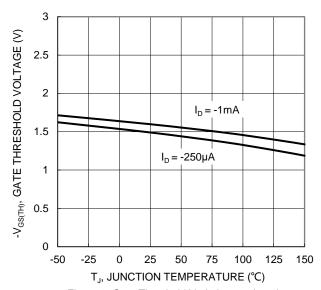


Figure 8. Gate Threshold Variation vs. Junction Temperature

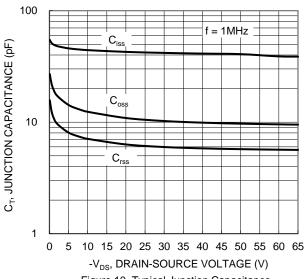


Figure 10. Typical Junction Capacitance

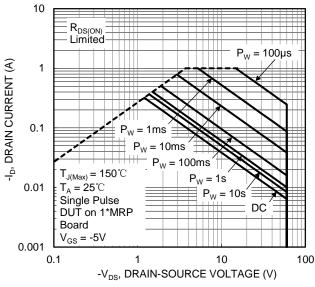


Figure 12. SOA, Safe Operation Area



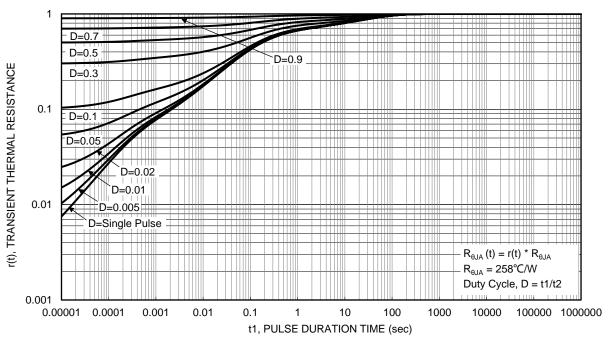


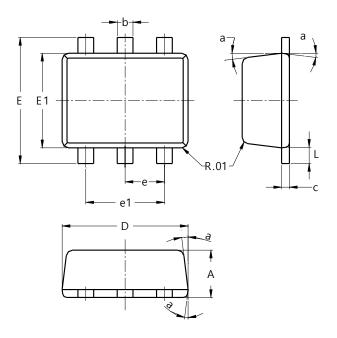
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT563**

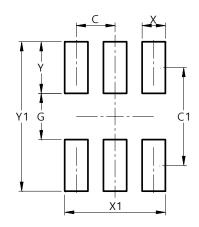


SOT563						
Dim	Min	Max	Тур			
Α	0.55	0.60				
b	0.15	0.30	0.20			
С	0.10	0.18	0.11			
D	1.50	1.70	1.60			
Е	1.55	1.70	1.60			
E1	1.10	1.25	1.20			
е			0.50			
e1	0.90	1.10	1.00			
L	0.10	0.30	0.20			
а	8°	9°	7°			
All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT563**



Dimensions	Value (in mm)			
С	0.500			
C1	1.270			
G	0.600			
Х	0.300			
X1	1.300			
Υ	0.670			
Y1	1.940			



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